Application of organic–graphene hybrids in high performance photodetectors

Jie Liu, Qiu Liang, Ruoyu Zhao, Shengbin Lei* and Wenping Hu*

High performance photodetectors play important roles in the improvement of innovative technologies in many fields, for instance, medicine, military, optical communication, environment monitoring, etc. Graphene functionalized with photo-active units has been investigated intensively due to the unique optical and electronic properties of the graphene material, which remarkably sustains and expands the graphene boom. This review focuses on the research progress in applications of organic–graphene hybrid films in photodetectors. We discuss the sensitization mechanisms of photo-response, fabrication of hybrid material devices and sensitization of graphene by different organic molecules. The organic–graphene hybrid materials hold great promise to realize high performance photodetectors with high responsivity and a fast response.

1 Introduction

Graphene, which is the most famous single-atom-thick two-dimensional (2D) material, has a honeycomb lattice composed of pure sp²-bonded carbon atoms. It has attracted intense attention in recent years due to its unique excellent properties such as strong light absorption as a single atomic layer, high carrier mobility, good transparency from the visible to the infrared range, tuneable optical properties, high thermal conductivity, good mechanical flexibility and large specific surface area. These outstanding optical, electronic and mechanical properties of graphene made it a great promising material in photodetectors. However, the intrinsically low absorption cross-section and zero band gap of graphene pose a serious problem for realization of high-performance photodetectors.

To improve the performance of graphene-based photodetectors, a facile sensitization method is urgently needed. Recently, more and more researchers have focused on developing graphene-based hybrid nanostructures to overcome the shortcomings of graphene, which provides new opportunities to fabricate high-performance optoelectronic devices. Hybrid nanostructures, which combine the...
unique properties of individual constituents, usually consist of two or more components with distinct functionality exhibiting optimized optoelectronic performance.\(^7,14,19\) Transition metal disulfides (TMDs, such as MoS\(_2\), WS\(_2\), etc.)\(^{25-27}\) quantum dots (such as PbS),\(^28\) gold nanoparticles\(^{29,30}\) and perovskites\(^{31,32}\) have been applied in sensitization of graphene and the responsivity of the device is significantly improved. In comparison with the above mentioned inorganic materials, organic–graphene hybrid films can be fabricated easily through a simple solution process over large areas on flexible substrates, and the abundance of organic materials also enables diverse choice to fabricate organic–graphene hybrids, which have attracted intense interest from researchers.

Graphene–organic hybrid materials are composites of graphene and organic photoactive materials, such as organic dyes, organic small molecules or polymer semiconductors.\(^33-46\) Light absorption in the spectral region of such graphene–organic hybrids is tunable by appropriately selecting the property of photoactive materials, which makes them more fascinating in the optoelectronic field. This review aims to give an overview of the progress in graphene–organic hybrid materials and their applications in high performance photodetectors. We will discuss from the aspects of photosensitization mechanisms, methods for hybrid material preparation, and the fabrication and characterization of devices. Given the large library of organic molecules, we believe that organic–graphene hybrid materials can serve as a versatile platform for high-performance, broadband photodetectors.

2 Sensitization mechanism of graphene-based photodetectors

Graphene, which is made out of sp\(^3\)-hybridized carbon atoms arranged on a honeycomb lattice, is a zero-band-gap semiconductor because the valence and conduction bands touch at the Brillouin zone corners (so-called Dirac or neutrality point).\(^47\)–\(^49\)

As a result, the zero band gap nature of graphene also leads to a low lifetime of carriers,\(^50,51\) thus photodetectors made of pure graphene lack gain mechanisms (e.g., carrier multiplication), which limits the improvement of some key parameters of photodetectors, for instance, the responsivity, noise equivalent power and quantum efficiency. As graphene is an intrinsic, atomically thin two-dimensional material, its conductance is very sensitive to electrostatic perturbation at the interface, thus making graphene a particularly promising material for high-gain photo-detection through a photogating effect.\(^52\) When graphene is functionalized by organic molecules, with a high absorption cross-section and spectrally tuneable absorption, the photogenerated charges in the organic molecules can transfer to graphene, while oppositely charged carriers remain trapped in the organic layer.\(^53,54\) The n-doping or p-doping effect are produced on graphene due to the properties of modified layer (Fig. 1). The carriers, which are trapped in the organic layer, lead to a photogating effect, where the presence of these charges changes the resistance of graphene through capacitive coupling. The high carrier mobility of graphene and the recirculation of charge carriers during the lifetime leads to ultra-high gain, which improves the quantum efficiency and photocurrent.\(^55,56\) The charge transfer is enhanced because of the difference in Fermi level, which increases the number of mobile charge carriers present in the graphene. Charge carriers are generated from the incident photon and electrons move from the graphene layer to the sensitization layer when the Fermi level of graphene is higher, whereas the holes transferred to the opposite direction. Excess carriers (electrons or holes) are injected into graphene and drift to the drain electrode under the bias between the source and drain, and the drift time is \(t_{\text{transit}}\). Because of the accumulation of carriers (electrons or holes) in graphene, the recombination process in the sensitized layer is hindered. Therefore, benefited from the ultrahigh mobility value of graphene (1000 cm\(^2\) V\(^{-1}\) s\(^{-1}\)) the recombination time \((\tau_{\text{lifetime}})\) in the activated layer is much longer than the transit time of the carriers (on the order of milliseconds compared to on the order of picoseconds). Then, the gain of photodetectors is given by \(G = \eta \tau_{\text{lifetime}}/\tau_{\text{transit}}\) in which \(\eta\) is the quantum efficiency.\(^57\)

![Wenping Hu](image)

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3 The fabrication of device

With the development of synthetic techniques and device fabrication methods, the rational integration of nanomaterials into various hybrid nanostructures with enhanced photodetection performances has been achieved, as summarized in Table 1.

3.1 The choice of substrate

The type of substrate has a great effect on the performance of the device. Typically, a Si/SiO$_2$ substrate is used when the photodetectors are fabricated, and a heavily doped Si wafer is employed as the gate electrode and a thermally grown 300 nm SiO$_2$ layer above it acts as a gate dielectric.\textsuperscript{58-61} The carrier density, and thus the conductivity of the channel can be modulated by an electric field applied on the gate. The surface of the SiO$_2$ dielectric can be modified with self-assembling monolayers composed of, e.g., n-octadecyltrimethoxysilane (ODTS) to decrease charge trapping caused by defects.

Conventional photodetectors based on inorganic materials are usually built on rigid and planar substrates, which limits their application in flexible devices. Phototransistors based on organic–graphene hybrid materials are easy to integrate with low-temperature processable flexible substrates over large areas, for instance, polyethylene terephthalate (PET) and polyimide (PI).\textsuperscript{62-66} Because of its good mechanical flexibility, graphene finds an irreplaceable position in the fabrication of flexible devices, and hence it is clear that a substrate with flexibility plays a very important role in developing a new type of device. Ki-Seok An et al. have successfully fabricated various graphene-based photodetectors via simple and efficient vapor-phase metalation of porphyrin on PET films and facilitated the development of new architectures for flexible graphene–organic devices.\textsuperscript{13}

3.2 Preparation of graphene

Both pristine graphene and chemically functionalized graphene are highly attractive for applications in optoelectronics and photo-energy conversion, due to their excellent electronic and optical properties as well as tuneable work functions.\textsuperscript{67-70} Synthesis of graphene is essential for its practical application in electronics and optoelectronics. Graphene can be obtained in different forms, and the most commonly used types are the exfoliated graphene layers\textsuperscript{71-75} and graphene grown by the chemical vapor deposition (CVD) method on various substrates.\textsuperscript{76-80}

The quality of graphene has a great influence on the electronic properties of hybrid materials. Mechanically exfoliated graphene is relatively clean in comparison with CVD-grown graphene and is widely used in the experimental studies of partial theoretical calculations.\textsuperscript{81-84} In addition to that, electrochemical exfoliated graphene can be easily fabricated into a large sized paper like form by applying brush painting of a concentrated graphene ink, which shows great promise for the industrial-scale synthesis of high-quality graphene for numerous advanced applications.\textsuperscript{85}

In particular, a large area, high-quality graphene film grown by the chemical vapor deposition (CVD) method is more promising for extensive applications because of its flexibility, high transparency, and electrical conductivity, and most importantly due to the fact that the number of layers can be controlled by adjusting growth conditions.\textsuperscript{86,87} After the CVD graphene is separated from the metallic catalyst where it is grown, it can be easily transferred to a dielectric substrate, which is a

Table 1 The key parameters of several recently reported organic–graphene hybrid photodetectors

<table>
<thead>
<tr>
<th>Photocative materials</th>
<th>Graphene</th>
<th>Fabrication of hybrid material</th>
<th>Substrate</th>
<th>Doping type</th>
<th>Responsivity (A W$^{-1}$)</th>
<th>Detectivity (Jones)</th>
<th>Maximum absorption wavelength (nm)</th>
<th>Determined wavelength (nm)</th>
<th>Ref.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Rhodamine derivatives</td>
<td>R6G</td>
<td>Exfoliated graphene CVD</td>
<td>Si/SiO$_2$</td>
<td>n</td>
<td>~460</td>
<td>10$^{10}$</td>
<td>530</td>
<td>400–980</td>
<td>34</td>
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<tr>
<td>R6G</td>
<td>CVD</td>
<td>Dip-coating (ODTS)</td>
<td>Si/SiO$_2$</td>
<td>p</td>
<td>~283</td>
<td>10$^{10}$</td>
<td>35</td>
<td>490</td>
<td>35</td>
</tr>
<tr>
<td>Rh110</td>
<td>CVD</td>
<td>Dip-coating</td>
<td>n</td>
<td>455</td>
<td>65</td>
<td></td>
<td>565</td>
<td></td>
<td>86</td>
</tr>
<tr>
<td>Rh101</td>
<td>CVD</td>
<td>Dip-coating</td>
<td>p</td>
<td>1031</td>
<td>685</td>
<td></td>
<td>685</td>
<td></td>
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<tr>
<td>Rh800</td>
<td>CVD</td>
<td>Dip-coating</td>
<td>10$^3$</td>
<td>10$^{10}$</td>
<td></td>
<td></td>
<td>760</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Rh110/Rh101/Rh800</td>
<td>CVD</td>
<td>Dip-coating</td>
<td>Si/SiO$_2$</td>
<td>n</td>
<td>~740</td>
<td>10$^{10}$</td>
<td>710</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Self-assembly</td>
<td>D-A type</td>
<td>CVD</td>
<td>Spin-coating</td>
<td>ITO/PEDOT:PSS</td>
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<td></td>
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<tr>
<td>molecule</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>710</td>
<td></td>
<td></td>
</tr>
<tr>
<td>ml-C$_6$-BTBT</td>
<td>CVD</td>
<td>CVD</td>
<td>Si/SiO$_2$</td>
<td>p</td>
<td>1.57 × 10$^4$</td>
<td></td>
<td>360</td>
<td>355</td>
<td>42</td>
</tr>
<tr>
<td>fl-C$_{6}$-BTBT</td>
<td>CVD</td>
<td>CVD</td>
<td>Si/SiO$_2$</td>
<td>p</td>
<td>4.76 × 10$^3$</td>
<td></td>
<td>360</td>
<td>355</td>
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<tr>
<td>Tetraphenylporphyrin</td>
<td>H$_2$TPP</td>
<td>CVD</td>
<td>Si/SiO$_2$</td>
<td>n</td>
<td>0.22</td>
<td></td>
<td>43</td>
<td></td>
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<tr>
<td>ZnP</td>
<td>CVD</td>
<td>Thermal (TE)</td>
<td>Si/SiO$_2$</td>
<td>p</td>
<td>0.34</td>
<td></td>
<td>43</td>
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<td></td>
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<tr>
<td>Ruthenium polypyridyl</td>
<td>Ru-Complex</td>
<td>CVD</td>
<td>Si/SiO$_2$</td>
<td>n</td>
<td>5.36</td>
<td></td>
<td>43</td>
<td></td>
<td></td>
</tr>
<tr>
<td>P3HT</td>
<td>CVD</td>
<td>Dip-coating</td>
<td>Si/SiO$_2$</td>
<td>n</td>
<td>10$^3$</td>
<td></td>
<td>37</td>
<td></td>
<td></td>
</tr>
<tr>
<td>P3HT/graphene/TiO$_2$</td>
<td>CVD</td>
<td>Spin-coating</td>
<td>Si/SiO$_2$</td>
<td>p</td>
<td>~</td>
<td></td>
<td>36</td>
<td></td>
<td></td>
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<tr>
<td>Spiropyran/merocyanine</td>
<td>Spiropyran</td>
<td>CVD</td>
<td>Si/SiO$_2$</td>
<td>n</td>
<td>~</td>
<td></td>
<td>38</td>
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<td></td>
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<tr>
<td>SWCNTs</td>
<td>Single-walled carbon nanotubes</td>
<td>Dispersed graphene</td>
<td>Si/SiO$_2$</td>
<td>n</td>
<td>~</td>
<td></td>
<td>39</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Biomaterials</td>
<td>Cytochrome c</td>
<td>CVD</td>
<td>Si/SiO$_2$</td>
<td>n</td>
<td>1.39 × 10$^4$/7.57 × 10$^4$</td>
<td></td>
<td>340, 410</td>
<td></td>
<td>41</td>
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</tbody>
</table>
commonly used method in device fabrication. Then using conventional photolithography and subsequent reactive ion etching (RIE) with O₂ plasma etching steps, channels with a certain width can be patterned on the substrate.88–96

3.3 The choice of sensitization material

Due to its large aromatic sp² lattice, free of dangling bonds, graphene is intrinsically chemically inert. The broad sensing potential of graphene can be activated by small molecules (such as rhodamine derivatives, C8-BTBT, tetraphenyl-porphyrin, ruthenium polydiyl), conjugated polymers, rare-earth components and even semiconductor nanoparticles (NPs)⁹⁷–⁹⁹ by covalent or noncovalent functionalization. Since non-covalent modification can be realized by a solution method (such as dip-coating, spin-coating, and drop-casting methods and dip-pen nanolithography) and thermal evaporation (TE) and thermal evaporation (TE), it is easier than covalent modification, in which sensitive materials are attached to graphene by an amidation reaction,¹⁰⁰–¹⁰⁴ cycloaddition reaction,¹⁰⁵–¹⁰⁸ free radical addition,¹⁰⁹,¹¹⁰ metal-catalysed coupling reactions¹¹¹,¹¹² and “click” chemistry.¹¹³–¹¹⁵ As there have been several review articles with regard to graphene functionalization,¹²³–¹²⁸ our focus herein is mainly on the non-covalent modification of small organic molecules on the surface of graphene.

Small organic molecules are an important class of materials for photodetector applications, offering wide material selection, excellent mechanical flexibility, and self-assembly or solution manufacturing capability. Recently, combining graphene with small photoactive functional components has attracted widespread attention, and several important photo-active moieties, including porphyrin, phthalocyanine, pyrenebutyrate, rhodamine 6G and so on, have been attached either to the edge or to the basal plane of the graphene surface. Hybrid nanostructures are usually synthesized by an epitaxial or solution processing method, which is suitable for large area preparation in succession with low cost.¹²⁹–¹³³

As for small organic molecules, a solution-based procedure is a simple, yet highly efficient method for decorating a large area graphene with the lowest cost. Dip-coating, drop-casting and spin-coating are the three common solution processing methods. In the dip-coating method, graphene is directly immersed in a solution of organic molecules. First-principles density functional theory (DFT) calculations indicate that the absorption of photoactive molecules and graphene has a great relationship with dipoles, binding energy, and interfacial layer spacing between the dyes and graphene.¹³⁶–¹⁴² Therefore, molecules with a high binding energy in the mixed solution have higher affinity when adsorbed with graphene, so it is difficult to control the components of organic hybridization. Compared to dip-coating, the drop-casting method can accurately control the hybrid components by direct deposition. Spin coating is one of the most common techniques for depositing thin films on substrates. It is used in a wide variety of industries and technology sectors. The advantage of spin-coating is its ability to quickly and easily produce very uniform films, ranging from a few nanometres to a few microns in thickness. The thickness and crystallinity of the active layer can be effectively adjusted by adjusting the rotation speed and concentration. Because of the simple and easy operation of the solution method, it has a good application prospect in the preparation of nanodevices.

Thermal evaporation (TE) is commonly used in the deposition of electrodes. It is also a reasonable method to control the thickness of the organic layers. TE is a convenient way for follow-up processing if multiple organic layered materials are needed. Ki-Seok An et al. deposited a metal-free H2TPP/graphene hybrid layer on a substrate to fabricate a H2TPP/graphene photodetector, and then metallized the H2TPP to form ZnTPP or Al[m]TPP by using diethylzinc (DEZ) and trimethylaluminum (TMA) precursors, respectively.¹³¹

3.4 Interaction between photoactive moieties and graphene

Most non-covalent functionalizations have been carried out via π–π stacking between conjugate structures with graphene and facilitate photo-excited charge transfer between the dye molecules and graphene, which results in the photoconductive gain. The deposition of the dye molecules can be performed using a simple dip-coating method. Using this method Jeong Ho Cho et al. prepared hybrid photodetectors by soaking a prepared graphene device in a mixture of three different dye molecules and then rinsing with deionized water.¹³² Interestingly, the spectra of the mixed hybrid films fabricated using this process showed only the Rh800 spectrum due to the higher affinity of Rh800 dyes to the graphene surface. However, the drop-casting and spin-coating processes enabled the adsorption of molecules (Rh101 and Rh110) having weak binding energies with graphene. The amount of sensitization molecules can be controlled through these processes, thereby adjusting the performance of the device.

4 The progress of organic–graphene hybrid photodetectors

4.1 Hybrid layer prepared by the solution method

4.1.1 Rhodamine based dye molecules. Combining graphene, which features a remarkably broad absorption band, with dye molecules (e.g., rhodamine 6G (R6G)), which have a high absorption cross-section, provides a very large photocurrent and an ultrahigh quantum efficiency.¹⁴³–¹⁴⁶ Chad A. Mirkin and coworkers patterned rhodamine 6G assembly by dip-pen nanolithography on graphene, and studied the transport and assembly properties of R6G on graphene (Fig. 2a).¹³ As a result, they found that, in general, the π–π stacking between the aromatic
Responsivity approaches: the device could operate at low voltages and the graphene photodetector displays several advantages over other performance optoelectronic devices (Fig. 2c). The dye-sensitized graphene based photodetectors offer spectral color selectivities with a high responsivity of $10^4$ A W$^{-1}$ and a detectivity of $\approx 10^{10}$ Jones at an illumination power of 10 nW. The hybrid system of graphene/organic dyes represents a versatile platform for the development of graphene-based optoelectronic devices.

Encouraged by the above results, Jeong Ho Cho and coworkers systematically investigated hybrid structures of organic dyes and graphene for the fabrication of photodetectors that display spectral color selectivity. Rh110, Rh101 and Rh800 with blue, green and red absorption profiles were deposited onto a graphene surface by dip-coating (Fig. 3a). The photodetectors based on the three different dye–graphene hybrid films exhibited the expected spectral color selectivities and maximum photocurrents were observed at wavelengths corresponding to the maximum absorption peak positions of each dye molecule (Fig. 3b and c). Herein, in order to broaden the spectral bandwidth over the full-color range, a resulting solution, consisting of Rh110, Rh101 and Rh800, is deposited onto a graphene channel (Fig. 3d). The mixed hybrid films exhibited a wide absorption spectral bandwidth that covered the absorption spectral ranges of each dye molecule (Fig. 3e). The mixed organic dye hybrid photodetectors offer spectral color selectivities with a high responsivity of $10^4$ A W$^{-1}$ and a detectivity of $\approx 10^{10}$ Jones at an illumination power of 10 nW. The hybrid system of graphene/organic dyes represents a versatile platform for the development of graphene-based optoelectronic devices.

Materials Chemistry Frontiers

**Fig. 2** (a) Schematic illustration depicting the patterning of rhodamine 6G (R6G) on graphene by dip-pen nanolithography (DPN). The inset shows the chemical structure of R6G. (b) $I_{DS}$–$V_G$ curves of the same graphene device (shown in the inset; the gold contact was prepared by evaporation of gold through a shadow mask) before (red) and after (blue) bulk functionalization with R6G. The bias voltage applied is 1 mV for both measurements. The Dirac point moved from $\sim 32$ to $\sim 6$ V. Copyright 2013, Nano Lett. (c) Schematic diagram and optical microscopy top-view images of the dye sensitized graphene photodetector. (d) Responsivity ($R$) and external quantum efficiency (EQE) as a function of the illumination power. The inset shows the photocurrent at $V_{GS} = 0$ V as a function of the illumination power. (e) Calculated joint density of states (DOS) of the graphene–R6G hybrid structure. The black line represents the DOS of the graphene. The positions of the HOMO (blue) and LUMO (red) levels were obtained from B3PW91 calculations of the physiosorbed R6G molecule. The HOMO of this structure was located at $-0.971$ eV and the LUMO was located at $1.150$ eV with respect to the location of the Dirac point of graphene. (f) UV-IR absorption spectra of R6G and R6G/graphene hybrid films. The red line was arbitrarily shifted upward to distinguish the absorbance of R6G from that of the R6G/graphene hybrid films. Copyright 2015, Carbon.

Encouraged by the above results, Jeong Ho Cho and coworkers developed a hybrid structure comprising organic dye molecules (e.g., rhodamine 6G) and graphene for the realization of high-performance optoelectronic devices (Fig. 2c). The dye-sensitized photodetectors respond to the incident illumination over a broad wavelength range ($400 < k < 1000$ nm), as well as with a high responsivity ($\sim 460$ A W$^{-1}$ at illumination power of 1 µW) (Fig. 2d). The photocurrent generated in the hybrid photodetector (on the order of mA) is much higher than that generated in a pristine graphene photodetector (on the order of µA). This hybrid graphene photodetector displays several advantages over other approaches: the device could operate at low voltages and the photoresponse does not vary significantly across the detector area. Apart from that, they find that both pristine R6G and the hybrid system display an absorption peak at $\sim 530$ nm corresponding to the direct transition from the HOMO to the LUMO of R6G, which means the adsorption of R6G does not change (Fig. 2e and f). This work provides a good demonstration for designing and preparing graphene photodetectors sensitized with dye molecules to realize wavelength selective detection properties.

Based on the above work, Jeong Ho Cho and coworkers systematically investigated hybrid structures of organic dyes and graphene for the fabrication of photodetectors that display spectral color selectivity. Rh110, Rh101 and Rh800 with blue, green and red absorption profiles were deposited onto a graphene surface by dip-coating (Fig. 3a). The photodetectors based on the three different dye–graphene hybrid films exhibited the expected spectral color selectivities and maximum photocurrents were observed at wavelengths corresponding to the maximum absorption peak positions of each dye molecule (Fig. 3b and c). Herein, in order to broaden the spectral bandwidth over the full-color range, a resulting solution, consisting of Rh110, Rh101 and Rh800, is deposited onto a graphene channel (Fig. 3d). The mixed hybrid films exhibited a wide absorption spectral bandwidth that covered the absorption spectral ranges of each dye molecule (Fig. 3e). The mixed organic dye hybrid photodetectors offer spectral color selectivities with a high responsivity of $10^4$ A W$^{-1}$ and a detectivity of $\approx 10^{10}$ Jones at an illumination power of 10 nW. The hybrid system of graphene/organic dyes represents a versatile platform for the development of graphene-based optoelectronic devices.

**Fig. 3** (a) Schematic illustration of an organic dye–graphene hybrid photodetector based on three different rhodamine-based dye molecules (Rh110: blue, Rh 101: green, and Rh800: red). The upper panel shows the chemical structures of the organic dyes used in this study. (b) Schematic illustration of the organic dye–graphene hybrid photodetector based on the mixture of dye molecules. (c) UV-vis absorption spectra of the mixed dye solutions and films fabricated using the dip-coating and drop-casting methods. (d) $I_0$ versus ($V_{GS}$=1.5 V $- V_{OS}$=800) plots of the hybrid photodetectors based on the mixed dyes under different illumination wavelengths at a fixed incident illumination power of 1 µW. (e) Photocurrents at the Dirac voltages in the hybrid photodetectors. Copyright 2016, Advanced Functional Materials.
in charge carrier transport. P3HT, which has been widely used in organic solar cell devices, typically absorbs visible light between 350 and 700 nm, and transports holes. Most sensitized graphene photoelectronic devices reported in the literature have typically demonstrated single-type carrier transport under light illumination (either n- or p-type), where the charge-transfer process is predominantly determined by the energy band alignment between graphene and the light-absorbing material. Hence, it will be particularly attractive if the carrier transport types (either n- or p-type) of a sensitized graphene transistor can be further controlled using selective optical excitation wavelengths, resulting in tuneable carrier transport in a graphene-based photoelectronic device. Chunjie Chen and coworkers proposed a novel device structure consisting of a graphene transistor sandwiched between two photoactive layers. In this phototransistor, the organic polymer poly(3-hexylthiophene) (P3HT) and inorganic TiO$_2$ (amorphous TiO$_2$) thin films act as the top and bottom doping layers, respectively, which is shown in Fig. 4a. The band alignments of the corresponding energy levels of the organic/inorganic hybrid doping (OIHD) platform, shown in the inset of Fig. 4b, suggests that the two opposite carriers might be able to transfer from the two photoactive layers to graphene when the device is under selective UV or visible light illumination. Experimental results show that the OIHD platform offers a unique advantage to provide controllable and reversible n-type or p-type doping on graphene by using selective-wavelength illumination. The concept of this novel device structure thus enables the control of the dual carrier-type transport behaviors of a graphene transistor by using wavelength-selective illumination, which may have great potential in future development of optically controlled electronic devices or integrated circuits.

### 4.1.3 Graphene–ruthenium complex hybrid photodetectors.

In energy conversion applications such as solar cells and water splitting, ruthenium polypyridyl complexes have been used as photoactive components for graphene or carbon nanotube (CNT)-based nanocomposites. These hybrid materials are known to facilitate separation and transport of electron–hole pairs, and reduce the recombination of charge carriers. These results have attracted researchers to exploit transition metal complexes as charge transfer materials in photodetectors. Joon Hak Oh and coworkers fabricated graphene-based photodetectors with a 4 nm-thick ruthenium complex hybrid (Fig. 5a and b). The monolayer graphene-based photodetectors exhibit pronounced n-type doping effect due to electron transfer via the metal–ligand charge transfer (MLCT) from the ruthenium complex to graphene, and shows an ultrahigh responsivity of $\approx 1 \times 10^5$ A W$^{-1}$ and a photoconductive gain of $\approx 3 \times 10^6$ under incident optical intensity of the order of sub-milliwatts (Fig. 5c and d). This methodology opens a viable way for enhancing the photoresponsivity of graphene-based FET-type photodetectors, and can be extended to construct various state-of-the-art photodetector platforms that are based on π-conjugated photoactive materials including organic small molecules, polymers, and carbon nanotubes.

#### 4.1.4 Structure switching molecule: spiropyran.

Photochromic molecules, which can switch between two (meta-) stable states when exposed to specific wavelengths, enable the use of a photonic input to modulate the electrical characteristics of solid-state devices. Spiropyran (SP, the uncharged, parent closed-ring isomer), a well-known photochromic molecule, comprises an indoline and a chromene moiety bound together via a spiro junction and oriented perpendicular with respect to one another (MC, the planar, highly conjugated structure). The spiropyran–merocyanine system can be switched between two stable states when exposed to specific wavelengths (ultraviolet light from SP to MC structure, and visible light for the reverse process), which has the potential for use as a photonic input to modulate the electrical characteristics of solid-state devices. Of particular interest is the possibility of exploiting photochromic molecules to modulate the conductance of (semi)conductive materials, eventually leading to light-switchable macroscopic devices. This approach was...
demonstrated for carbon nanotubes, graphene and polymers. Hyeon Suk Shin and coworkers designed and synthesized pyrene-SP molecules, and then demonstrated defect-free n-doping of graphene through functionalization with SP by noncovalent bonding (Fig. 6i-a and b).\textsuperscript{38} The conformational change between SP and MC upon UV and visible light irradiation affected the electrical properties of graphene.\textsuperscript{175} They demonstrated a reversible light-modulated Dirac point of graphene according to UV and visible light exposure (Fig. 6i-c and d). This allows for new possibilities of doping control methods using functionalization of graphene with photochromic molecules.

At present, in the study of SP molecules, the isomerization of molecular structure is inferred based on electrical properties, without a direct, real-space visualization of the (supra)molecular structural changes induced by the switching events. However, scanning tunneling microscopy (STM) is a good way to acquire the real-space images of supramolecular assemblies of photochromic molecules. Paolo Samorì and coworkers achieved exquisite control over events taking place from the molecular level to the device scale by combining different experimental and theoretical approaches (Fig. 6ii-a).\textsuperscript{39} They designed and synthesized a spiropyran (SP) derivative bearing an 18-carbon long alkyl chain, and monitored the evolution of the molecular arrangement with sub-nm resolution by STM imaging in air and at room temperature on dry films on HOPG to study the photoswitch of the SP derivative down to the monolayer limit. As for the STM image, photochromic molecules assembled at the surface of single layer graphene generate an atomically precise superlattice in which a major structural rearrangement is obtained by light-induced collective isomerization (Fig. 6ii-b–d). As a result, the rearrangement causes a reversible shift in the work function of two-dimensional materials (2DMs), readable in devices as significant doping, which is also fully reversible (Fig. 6ii-e and f).

This work offers a yet unexplored solution to supramolecular electronics, in which atomic precision in molecular self-assembly is tailored not to optimize charge transport but rather to control it by imparting new properties to a material, enabling the realization of multifunctional, high-performance devices.

### 4.1.5 Single-walled carbon nanotube (SWCNTs)

Single-walled carbon nanotubes (SWCNTs) are considered as one of the most promising candidates for next-generation photoelectronic devices due to their high carrier mobility, high thermal conductivity, large absorption coefficient, and excellent chemical stability.\textsuperscript{176,177} The bandgaps of semiconducting SWCNTs are inversely proportional to their diameter (from 0.5 to 1.2 eV when the diameters range from 0.7 to 2.0 nm),\textsuperscript{178} with which the wavelength of SWCNT-based photodetectors can be tuned by controlling the diameters. In addition, it has been theoretically and experimentally demonstrated that multiple electron–hole pairs can be generated from one high-energy photon in SWCNTs, which provides the possibility of fabricating high-performance photoelectronic devices using different nanotube types as a light absorber, such as individual SWCNTs, aligned SWCNT arrays, SWCNT networks, SWCNT films or even hybrid materials (such as SWCNT/C\textsubscript{60}).\textsuperscript{179} In addition to 0D C\textsubscript{60}, 2D graphene has also been demonstrated to enhance significantly the carrier separation by forming Schottky junctions with SWCNTs due to exceedingly high carrier mobility and thermal conductivity.\textsuperscript{180,181} However, the intrinsic large dark current of graphene and the poor optical absorption of the ultrathin SWCNT layer inhibit further improvement in the detectivity and on–off ratio of the devices. Zhang et al. demonstrate a carbon-based photodetector using SWCNT/separated graphene (SGR) hybrid networks, which is illustrated in Fig. 7a and b.\textsuperscript{40} In this hybrid material, graphene nanosheets were connected by SWCNTs with the dip-coating method to form a continuous network. The discontinuous graphene nanosheets exhibit a much lower dark current than the SWCNT/graphene film, which enhances the current to a large extent. Moreover, the efficient charge transfer between SWCNTs and SGR nanosheets can significantly reduce the recombination probability for photogenerated electrons and holes, thus enhancing the photoresponsivity of the photodetector.

As for the result, the device exhibits an excellent broadband photoelectric response from the visible to the NIR range (405–1064 nm) with a high photoresponsivity of > 3000 A W\textsuperscript{-1} and a fast response time of 44 μs, which is higher than that of other
SWCNT-based devices (Fig. 7c and d). This architecture strategy not only demonstrates great potential for high-performance all carbon photodetectors but also offers a universal approach to fabricate high-performance semiconductor/graphene hybrid photodetectors.

### 4.1.6 Biomaterials: cytochrome c

van der Waals heterojunctions that interface graphene with functional biomolecules can provide a unique scheme for biomolecule-based circuits on a large scale. High-performance optoelectronics through atomic-scale interface design can provide high-efficiency exciton dissociation and charge transfer as demonstrated in inorganic van der Waals heterojunctions consisting of semiconductor nanostructures on graphene or other 2D materials. A biomolecule/graphene van der Waals heterojunction provides a generic platform for designing high-performance, flexible, and scalable optoelectronics. A key challenge in controllable attachment is the formation of a desired interfacial electronic structure by the biomolecules for a high-efficiency optoelectronic process involving photoabsorption, exciton dissociation, carrier transfer, and transport. In Wu’s work, the modification of graphene with a well characterized protein molecule cytochrome c (Cyt c) was achieved by the print method on the channel of graphene field-effect transistors (GFETs) (Fig. 8a). Benefitting from the electrostatic field in graphene, the orientation of the Cyt c molecules can be controlled on the polarity-controlled GFET channel with a desired interfacial electronic structure for exciton dissociation and charge transfer by the built-in electric field established through the band-edge alignment at the Cyt c/GFET interface (Fig. 8b and c). This Cyt c/GFET van der Waals heterojunction photodetector combines the photoabsorption of biomolecule Cyt c with the superior carrier mobility of graphene, enabling a high-efficiency optoelectronic process as illustrated in the high photoconductive gain of up to $1.1 \times 10^4$ and the high responsivity of 1.39 $\times 10^4$ A W$^{-1}$ at 340 nm and 7.57 $\times 10^3$ A W$^{-1}$ at 410 nm (Fig. 8d). In addition, the biomolecule/graphene van der Waals heterojunction nanohybrid structure integrates the spectral tunability of biomolecules for photoabsorption, GFET gate tunability of the interfacial band-edge alignment for optimal exciton dissociation and charge transfer, and high carrier mobility of graphene for charge transport. The approach of printable biomolecules on GFETs will pave a way for larger-scale fabrication of low-cost, high-performance nanohybrid optoelectronic devices.

### 4.2 Hybrid layer prepared by self-assembly

#### 4.2.1 Physical vapor deposition (PVD) for ultrathin organic crystals

Organic field effect transistors (OFETs) attract much attention for next generation devices. To achieve a good performance of OFETs, improvements of crystallinity and control of the molecular orientation of the active material are essential. For this purpose, Xinran Wang et al. have epitaxially grown C8-BTBT layers on prepatterned graphene field-effect transistors (FETs) with Au electrodes to fabricate an ultrathin epitaxial organic crystal/graphene hybrid for highly efficient phototransistors (Fig. 9a). The thickness of the C8-BTBT layer could be effectively controlled by this method (Fig. 9b). Benefitting from the high quality of organic crystals and interfaces, which is a unique feature of vdW epitaxy (van der Waals epitaxy), the phototransistors exhibit a strong photoresponse down to the limit of monolayer organic semiconductors, with responsivity higher than $10^4$ A W$^{-1}$, response time of $\approx 25$ ms, and photoconductive gain over $10^8$. The roughly linear relationship of EQE and gain with film thickness up to approximately seven layers suggested that excitons in the top C8-BTBT layers could still diffuse to the interface and dissociate efficiently, implying an exciton diffusion length of at least $\approx 20$ nm. Due to the exponentially
H2TPP-, ZnTPP-, and Al(III)TPP-graphene photodetectors are of porphyrin, as shown in Fig. 10a–d. The photoresponsivities of via photodetectors of concept, they successfully fabricated various graphene-based networks and 2D materials grant access to device fabrication machinery known to man. Bottom-up modular self-assembled self-assembly to fabricate the most complex molecularly precise film transistors and memory devices). Advanced flexible and transparent graphene devices (e.g. research described herein may allow for the realization of the fabrication of graphene-based electronics. As such, the devised synthesis method provides a high degree of flexibility in 50 mV bias voltage (Fig. 10e and f). It should be noted that the 0.22 A W \(^{-1}\)/C0 longer lifetime in thicker samples, they observed an exponential increase of \(G_{ph}\) as a function of C8-BTBT thickness, despite the large scatter of data points (presumably, because the number of layers does not reflect the film morphology) (Fig. 9b and c). Given the large library of organic molecules, they believe that epitaxial ultrathin organic crystals on graphene can serve as a versatile platform for high-performance, broadband phototransistors.

4.2.3 Self-assembly of D–A type molecule. Nature employs simple and efficient vapor-phase metalation for the controllable fabrication of photodetectors based on graphene–organic hybrid thin films. In Ki-Seok An and coworkers’ work, metal-free H\(_2\)TPP or metalloporphyrins (Al(III)TPP and ZnTPP) are synthesized by thermal evaporation and vapor phase metalation which are utilized for tunable functionalization of graphene-based devices. As a proof of concept, they successfully fabricated various graphene-based photodetectors via simple and efficient vapor-phase metalation of porphyrin, as shown in Fig. 10a–d. The photoresponsivities of H2TPP-, ZnTPP-, and Al(III)TPP-graphene photodetectors are 0.22 A W \(^{-1}\), 0.54 A W \(^{-1}\), and 5.36 A W \(^{-1}\), respectively, at a 50 mV bias voltage (Fig. 10e and f). It should be noted that the devised synthesis method provides a high degree of flexibility in the fabrication of graphene-based electronics. As such, the research described herein may allow for the realization of advanced flexible and transparent graphene devices (e.g., thin film transistors and memory devices).

4.2.3 Self-assembly of D–A type molecule. Nature employs self-assembly to fabricate the most complex molecularly precise machinery known to man. Bottom-up modular self-assembled networks and 2D materials grant access to device fabrication with molecular precision. Heteromolecular, two-dimensional self-assembled networks provide a route to spatially organize different building blocks relative to each other, enabling molecularly precise fabrication. Sarah Wieghold and coworkers fabricated devices with molecular precision by a near-to-monolayer architecture on graphene, which consist of a self-assembled terylene-based dye and melamine (Fig. 11a and b). The molecular architecture of the self-assembled sensitizing layer approaches atomically defined spatial disposition of all components. In this work, CVD graphene is successfully transferred onto a transparent diamond, and terylene diimide (TDI) derivative (1) and melamine (2) which with a chromophore are self-assembled as a network on the surface of graphene. The assembly at the graphene–diamond interface shows an absorption maximum at 740 nm (Fig. 11c), whereby the photoreponse can be measured with a gallium counter electrode. Employing 19 mW cm\(^{-2}\) irradiation intensity at 710 nm, the photocurrent and open-circuit voltage are 0.5 nA and 270 mV, respectively (Fig. 11d). By estimation of the tunnelling area, their non-optimized device element configuration yields an incident photon to electron efficiency (IPCE) at 710 nm as high as 0.6% in air, opening novel avenues towards tandem photovoltaics from monolayer-thin sensitizers. What’s more, this work motivates rapid progress in molecular engineered manufacturing and monolayer by monolayer molecular printing methods, which potentially grants access to exponential optimization of device performance.

In addition, Thomas P. Russell and coworkers alternately installed typical triphenylamine (TPA) as an electron-rich unit and BTTH\(_2\) (4,7-bisthienyl-2,1,3-benzothiadiazole) as an electron-deficient unit into acetylene linked conjugated macrocycles (Fig. 12). STM experiments confirmed that the two shape-persistent

Fig. 9 (a) Schematic illustration of a typical C8-BTBT-graphene phototransistor. (b) The AFM images of a graphene FET before (left) and after (right) C8-BTBT epitaxial growth. The device is mostly covered with IL + 1L C8-BTBT as reflected from the measured height increase by 2.5 nm. Scale bars: 2 μm. (c) EQE (red triangles) and IQE (blue squares) as a function of average number of C8-BTBT layers for all the measured devices (laser power, 100 μW cm\(^{-2}\)). The red dashed line reflects the linear increase of EQE. (d) Photoconductive gain (\(G_{ph}\)) as a function of average number of C8-BTBT layers for all the measured devices (laser power, 100 μW cm\(^{-2}\)). The red dashed line reflects the exponential increase of \(G_{ph}\). Copyright 2016, Advanced Materials.

Fig. 10 (a–d) Schematic representation of H2TPP– and metalloporphyrin–graphene hybrid film formation. (e) Photoresponsivity of H2TPP-, ZnTPP-, and Al(III)TPP-graphene-based devices as a function of the source–drain bias voltage during exposure to light with a power density of 31.7 W m\(^{-2}\). (f) Photoresponsivity as a function of the light power density; a bias voltage of 2 V was used for the measurements. Copyright 2016, Nanotechnology.
cyclic molecules showed interesting concentration-controlled self-assembling behaviour at the solid/liquid interface and could capture fullerenes within their inner cavities to form host–guest coassembly structures. Moreover, in the new stable complexes, D–A conjugated cyclic molecules act as donors and fullerene (C70) as an acceptor to form new donor-acceptor heterojunctions with big shape complementarity D/A molecular interfaces. More importantly, this work provides further opportunities to achieve high-efficiency organic solar cells through utilizing D–A conjugated cyclic molecules as donor materials with PCBM to control the morphology of the active layer.

### 4.3 Covalent organic frameworks (COFs)

Covalent organic frameworks (COFs), consisting of molecular building blocks connected by covalent bonds, are a new class of porous architectures that allow the integration of organic units with atomic precision into long-range-ordered two- or three-dimensional structures. Owing to the covalent linkage of the components, as well as the elaborately controlled structure, including the nature of the structural unit molecule, COFs are promising for photodetectors. Theoretical calculations have predicted the attractive properties of 2D conjugated polymers for more than two decades. In fact, the Jiang group has already explored the photoelectric properties of bulk COFs in recent years. They show that metallophthalocyanine, porphyrin and its self-assembly materials have great potential in photovoltaic devices. However, the poor dispersibility of bulk COFs is the major drawback in their optoelectronic applications.

2D COFs with layered structures stacked together through van der Waals interactions are ideally suited for efficient energy storage and charge transport. The surface confined synthesis on single-crystal surfaces is a simple while efficient methodology for the preparation of 2D COFs with single layer thickness, and easy control of the number of layers, as well as the bandgap. Lei and coworkers designed a simple while efficient methodology for the preparation of 2D COF(BTA–PDA) at an octanoic acid/graphene interface. As the synthesized 2D COF film is adsorbed on graphene, there is a strong coupling between surface COF(BTA–PDA) and graphene, which was revealed by the contrast of surface COF(BTA–PDA) on different parts of the graphene surface (Fig. 13a and b). The shape of the density of states (DOS) of the G-surface COF(BTA–PDA) near the Fermi level is dominated by graphene and contains a strong coupling between surface COF(BTA–PDA) and graphene.
the band gap of the G-surface COF_{BTA-PDA} complex is very small (0.081 eV), which indicate that the imine based surface COFs are intriguing two dimensional organic semiconductors with a tuneable band gap (Fig. 13c and d). It provides a potential technological approach to sensitize graphene with 2D COFs with controllable thickness for applications in flexible devices.

5 Conclusion and perspectives

Graphene, a single layer 2D structure, possesses excellent physical and chemical properties, such as high mobility and thermal conductivity, great mechanical strength and extremely large specific surface area. However, pristine graphene shows a limited application in photodetectors because of its low optical absorption and zero band gap. In order to improve the performance of graphene-based photodetectors, a series of methods have been used to achieve high-quality photodetection, including both device geometry and materials engineering.

Over the past few decades, the booming of studies on developing chemically functionalized graphene created great opportunities for the development of hybrid thin film transistors, and numerous dramatic and unprecedented results are demonstrated in front of the world, including many excellent results using photo-active moieties to functionalize graphene. In this article, we have systematically introduced the application of graphene functionalized with organic molecules in photodetectors in three progressive parts: the gain mechanism in optical gain, the integration of device and the progress in applications of hybrid films in photodetectors. Based on these contents, it is worth noting that the aforementioned graphene hybrid nanostructures will play an important role in improving the performance and extending the function of traditional photodetectors.

Although many successful examples have been demonstrated, large-scale, practical applications of graphene-based hybrid materials in photodetection and photodetectors still have a long way to go. Furthermore, in order to achieve the preparation of a graphene-based photodetector with a large area, stable performance and commercial application, there are still some problems that should be optimized. Firstly, how to produce high-quality, large-area, low-defect (structure defects or oxidation sites) graphene or graphene sheets is still a challenge in the preparation and improvement of photodetectors and to go into the mechanism of graphene-based photodetectors. Therefore, new methodologies for milder exfoliation and chemical modification of graphene are still needed to tackle this problem. Secondly, since graphene cannot directly generate long-lived charge carriers in photoelectron light energy conversion applications, it is necessary to make more carefully designs of chemical functionalization and linking groups, in order to take advantage of the electronic interaction between graphene and photoactive groups. Multi-functionalized graphene materials with different small organic molecules are expected to provide new ideas for designing charge transfer systems for light energy conversion. Moreover, with the development of nanotechnology, integrated nanosystems and multifunction circuits have attracted much research attention due to their potential applications in many fields. Thus, the development of integratable nanophotodetectors is highly needed.

For many types of detectors, performance parameters have already been demonstrated at levels that are superior or on a par with existing technologies. To move forward, the ultrahigh photoresponsivity or ultrafast response speed of graphene-based photodetectors is still a challenge to have them both in a single device. This is a prerequisite for graphene-based photodetectors to realize commercialization. In addition, the prospect of commercialization depends not only on the performance of the detectors, but also on their unique strengths and capabilities, as well as the ability to achieve large-scale, high-quality GRM production at low cost, and the creation of large-energy and long-lived photons and integration of electronic platforms such as CMOS technology.

Conflicts of interest

There are no conflicts to declare.

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Notes and references
